

Title of Change:	Capacity Expansion of Assembly and Test operation Malaysia.	Capacity Expansion of Assembly and Test operations of ON Suzhou for D2PAK package to ON Seremban, Malaysia.		
Proposed first ship date:	31 December 2019			
Contact information:	Contact your local ON Semiconductor Sales Office or < <u>SitiNurhaza.MohdRamli@onsemi.com</u> >			
Samples:	Contact your local ON Semiconductor Sales Office or < <u>PCN.samples@onsemi.com</u> > Sample requests are to be submitted no later than 30 days from the date of first notification, Initial PCN or Final PCN, for this change. Samples delivery timing will be subject to request date, sample quantity and special customer packing/label requirements.			
Additional Reliability Data:	Contact your local ON Semiconductor Sales Office or < <u>MohdHairwan.MdNor@onsemi.com</u> >			
Type of notification:	This is a Final Product/Process Change Notification (FPCN) sent to customers. FPCNs are issued 90 days prior to implementation of the change. ON Semiconductor will consider this change accepted, unless an inquiry is made in writing within 30 days of delivery of this notice. To do so, contact < <u>PCN.Support@onsemi.com></u>			
Change Part Identification:	Affected products will be identified by Marking code.			
Change Category:	Wafer Fab Change 🔽 Assembly Change	✓ Test Change Other		
Change Sub-Category(s): Image: Manufacturing Site Addition Image: Manufacturing Site Transfer Image: Manufacturing Process Change		 Datasheet/Product Doc change Shipping/Packaging/Marking Other: 		
Sites Affected:	ON Semiconductor Sites: ON Seremban, Malaysia ON Suzhou, China	External Foundry/Subcon Sites: None		
Description and Purpose:				

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This is the final product change notification (FPCN) of IPCN22746X announcing that ON Semiconductor is expanding Assembly and Test Operations of ON Suzhou for D2PAK package to ON Seremban, Malaysia.

No change on existing OPN. There will be two separate BOMs for ON Suzhou, China and ON Seremban, Malaysia.

	Before Change Description	After Change Description		
Assembly Site	ON Suzhou	ON Suzhou	ON Seremban	
LeadFrame	TSP	TSP	SDI	
Die Attach	PB92.5,SN5AG2.5	PB92.5,SN5AG2.5	Pb95Sn5	
	PB93.5SN5AG1.5	PB93.5SN5AG1.5	PD955115	
Bond Wire	Heraeus 99.99% Aluminium wire	Heraeus 99.99% Aluminium wire	Tanaka 99.99% Aluminium wire	
Mold Compound	CEL8240HF10FC	CEL8240HF10FC		
	EME6600CS	EME6600CS	G700HF	
	SG8200DL	SG8200DL		



Document # : FPCN22746X Issue Date: 24 September 2019

	From		То
	ON Suzhou	ON Suzhou	ON Seremban
Product marking change QFET and MOSFET)	Line1: \$Y&Z&3&K Line2: Specific part number Line3: Specific part number Remark: \$Y = ON Semiconductor Logo &Z = Assembly Plant Code &3 = Data Code (Year & Week) &K = Lot	Line1: \$Y&Z&3&K Line2: Specific part number Line3: Specific part number Remark: \$Y = ON Semiconductor Logo &Z = Assembly Plant Code &3 = Data Code (Year & Week) &K = Lot	Line 2: Specific part number Trace code: \A/(YWW) Remark: A = Assembly Site Y = Year WW = Work Week
roduct marking change (Ultrafast Diode)	Line1: \$Y&Z&3&K Line2: Specific part number Remark: \$Y = ON Semiconductor Logo &Z = Assembly Plant Code &3 = Data Code (Year & Week) &K = Lot	Line1: \$Y&Z&3&K Line2: Specific part number Remark: \$Y = ON Semiconductor Logo &Z = Assembly Plant Code &3 = Data Code (Year & Week) &K = Lot	Trace code: AYWW Line 2: Specific part number Remark: A = Assembly Site Y = Year WW = Work Week

Reliability Data Summary:

QV DEVICE NAME: FQB12P20TM (QFET)

RMS	: <u>S56028</u>
PACKAGE	: <u>D2PAK</u>

Test	Specification	Condition	Interval	Result
HTRB	JESD22-A108	Ta = 150 °C, bias = 80% of rated V	1008 hrs	0/231
HTGB	JESD22-A108	Ta = 150 °C, bias = 80% of rated V	1008 hrs	0/231
HTSL	JESD22-A103	Ta = 150 °C	1008 hrs	0/231
IOL	MIL-STD-750 (M1037) AEC-Q101	Ta=+25°C, delta Tj=100°C max, Ton = Toff = 3.5min	8572 cyc	0/231
TC	JESD22-A104	Ta = -55°C to +150°C	1000 cyc	0/231
UHAST	JESD22-A118	85°C, 85% RH, 18.8psig, unbiased	96 hrs	0/231
H3TRB	JESD22-A101	85°C, 85% RH, bias = 80% of rated V or up to maximum 100V	1008 hrs	0/231
РС	J-STD-020 JESD-A113	MSL 1 @ 245 °C		0/924



RSH	JESD22- B106	Ta = 265°C, 10 sec		0/90
SD	JSTD002	Ta = 245°C, 10 sec		0/45
RMS	: <u>FDB082N15A (MV5-MOSFET</u> : <u>S56050</u> : <u>D2PAK</u>	נ		
Test	Specification	Condition	Interval	Result
HTRB	JESD22-A108	Ta = 150 °C, bias = 80% of rated V	1008 hrs	0/231
HTGB	JESD22-A108	Ta = 150 °C, bias = 80% of rated V	1008 hrs	0/231
HTSL	JESD22-A103	Ta = 150 °C	1008 hrs	0/231
IOL	MIL-STD-750 (M1037) AEC-Q101	Ta=+25°C, delta Tj=100°C max, Ton = Toff = 3.5min	8572 cyc	0/231
ТС	JESD22-A104	Ta = -55°C to +150°C	1000 cyc	0/231
UHAST	JESD22-A118	85°C, 85% RH, 18.8psig, unbiased	96 hrs	0/231
H3TRB	JESD22-A101	85°C, 85% RH, bias = 80% of rated V or up to maximum 100V	1008 hrs	0/231
РС	J-STD-020 JESD-A113	MSL 1 @ 245 °C		0/924
RSH	JESD22- B106	Ta = 265°C, 10 sec		0/90
SD	JSTD002	Ta = 245°C, 10 sec		0/45

QV DEVICE NAME:FFB20UP30DNTM (Ultrafast Diode)RMS: 555729

PACKAGE

E : <u>D2PAK</u>

Test	Specification	Condition	Interval	Result
HTRB	JESD22-A108	Ta = 150 °C, bias = 100% of rated V	1008 hrs	0/231
HTSL	JESD22-A103	Ta = 175 °C	1008 hrs	0/231
IOL	MIL-STD-750 (M1037) AEC-Q101	Ta=+25°C, deltaTj=100°C max, Ton = Toff = 3.5min	8572 сус	0/231
TC	JESD22-A104	Ta = -65°C to +150°C	1000 cyc	0/231
AC	JESD22-A102	121°C, 100% RH, 15psig, unbiased	96 hrs	0/231
H3TRB	JESD22-A101	85°C, 85% RH, bias = 80% of rated V or up to maximum 100V	1008 hrs	0/231
PC	J-STD-020 JESD-A113	MSL 1 @ 245 °C		0/924
RSH	JESD22- B106	Ta = 265°C, 10 sec		0/90
SD	JSTD002	Ta = 245°C, 10 sec		0/45



Electrical Characteristic Summary:

Electrical characteristics are not impacted

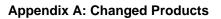
List of Affected Parts:

Note: Only the standard (off the shelf) part numbers are listed in the parts list. Any custom parts affected by this PCN are shown in the customer specific PCN addendum in the PCN email notification, or on the PCN Customized Portal.

Part Number	Qualification Vehicle
FDB082N15A	FDB082N15A
FDB088N08	FDB082N15A
FDB088N08-F141	FDB082N15A
FDB110N15A	FDB082N15A
FDB120N10	FDB082N15A
FDB14N30TM	FQB12P20TM
FDB150N10	FDB082N15A
FDB3502	FDB082N15A
FDB390N15A	FDB082N15A
FDB8444	FDB082N15A
FDB8447L	FDB082N15A
FDB86102LZ	FQB12P20TM
FFB20UP30DNTM	FFB20UP30DNTM
FQB11P06TM	FQB12P20TM
FQB12P20TM	FQB12P20TM
FQB19N20CTM	FQB12P20TM
FQB19N20LTM	FQB12P20TM
FQB19N20TM	FQB12P20TM
FQB22P10TM	FQB12P20TM
FQB27P06TM	FQB12P20TM
FQB30N06LTM	FQB12P20TM
FQB33N10LTM	FQB12P20TM
FQB33N10TM	FQB12P20TM
FQB44N10TM	FQB12P20TM
FQB50N06LTM	FQB12P20TM
FQB50N06TM	FQB12P20TM
FQB7P20TM	FQB12P20TM
FQB8P10TM	FQB12P20TM



FQB9P25TM	FQB12P20TM
IRFW630BTM-FP001	FQB12P20TM
ISL9R1560S3ST	FFB20UP30DNTM
ISL9R860S3ST	FFB20UP30DNTM



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Product	Customer Part Number	Qualification Vehicle	
FDB082N15A		FDB082N15A	
FDB088N08		FDB082N15A	
FDB110N15A		FDB082N15A	
FDB120N10		FDB082N15A	
FDB14N30TM		FQB12P20TM	
FDB150N10		FDB082N15A	
FDB3502		FDB082N15A	
FDB390N15A		FDB082N15A	
FDB8444		FDB082N15A	
FDB8447L		FDB082N15A	
FDB86102LZ		FQB12P20TM	
FFB20UP30DNTM		FFB20UP30DNTM	,
FQB11P06TM		FQB12P20TM	
FQB12P20TM		FQB12P20TM	
FQB19N20CTM		FQB12P20TM	
FQB19N20LTM		FQB12P20TM	,
FQB19N20TM		FQB12P20TM	
FQB22P10TM		FQB12P20TM	
FQB27P06TM		FQB12P20TM	,
FQB30N06LTM		FQB12P20TM	
FQB33N10LTM		FQB12P20TM	
FQB33N10TM		FQB12P20TM	
FQB44N10TM		FQB12P20TM	
FQB50N06LTM		FQB12P20TM	
FQB50N06TM		FQB12P20TM	
FQB7P20TM		FQB12P20TM	
FQB8P10TM	ĺ	FQB12P20TM	
FQB9P25TM		FQB12P20TM	
ISL9R1560S3ST		FFB20UP30DNTM	
ISL9R860S3ST		FFB20UP30DNTM	